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Vishay Semiconductors

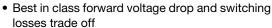
Hyperfast Rectifier, 30 A FRED Pt® G5



PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V_{R}	1200 V				
V _F at I _F at 125 °C	1.7 V				
t _{rr}	32 ns				
T _J max.	175 °C				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

Hyperfast and optimized Q_{rr}





- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 103 °C, D = 0.50	30				
Non-repetitive peak surge current	I_{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	250	Α			
Repetitive peak forward current	I _{FRM}	$T_C = 103 ^{\circ}C, D = 0.50, f = 20 \text{kHz}$	60				
Operating junction and storage temperature	T_J , T_{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	$I_R = 100 \mu A$	1200	-	-			
Forward voltage	V _F	I _F = 30 A	-	1.9	2.3	V		
		I _F = 30 A, T _J = 125 °C	-	1.7	-			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	50	μА		
neverse leakage current		$T_J = 125$ °C, $V_R = V_R$ rated	-	-	500			
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	113	-	ns	
		T _J = 125 °C		-	175	-	1	
Dealeman	I _{RRM}	T _J = 25 °C	$I_F = 20 \text{ A}$ $dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	17	-	Α	
Peak recovery current		T _J = 125 °C		-	26	-		
Deviance receiver above	Q _{rr}	T _J = 25 °C		-	850	-	nC	
Reverse recovery charge		T _J = 125 °C		-	2150	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 800 V	-	85	-	ns A	
neverse recovery time		T _J = 125 °C		-	132	-		
Dools recovery commont	I _{RRM}	T _J = 25 °C		-	30	-		
Peak recovery current		T _J = 125 °C		-	43	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	1350	-	nC	
		T _J = 125 °C		-	3215	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.2	°C/W		
Maight			-	2.0	'n	g		
Weight			-	0.07	ï	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-220AC 2L	E5TH3012					

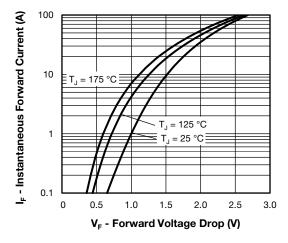


Fig. 1 - Typical Forward Voltage Drop Characteristics

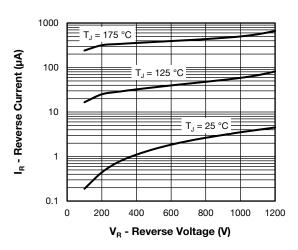


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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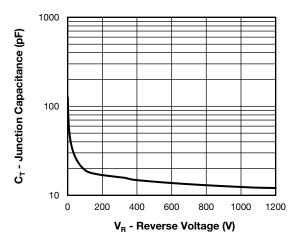


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

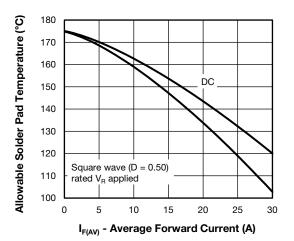


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

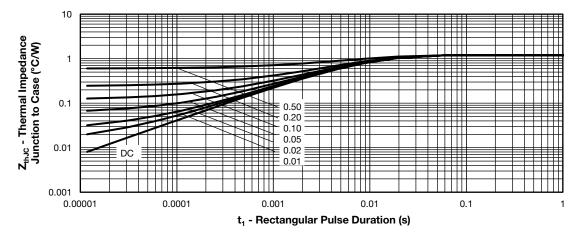


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

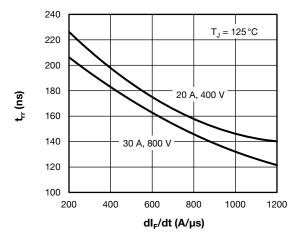


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

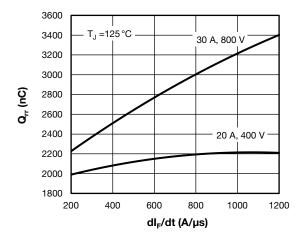


Fig. 7 - Typical Stored Charge vs. dl_F/dt

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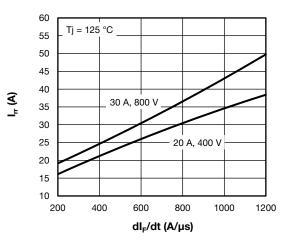


Fig. 8 - Typical Recovery Current vs. dl_F/dt

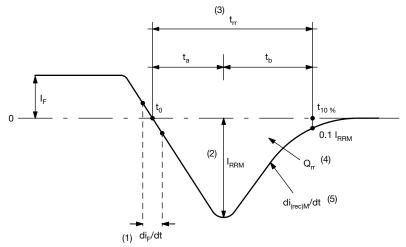


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ Q_{rr} area under curve defined by t_0 and $t_{10\,\%}$

$$Q_{rr} = \int_{t_0}^{\tau_{10} \%} I(t) dt$$

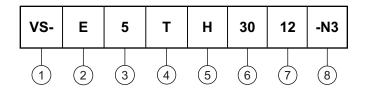
 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

- 5 = Fred generation 5

4 - Package:

T = TO-220AC 2L

5 - H = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (12 = 1200 V)

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5TH3012-N3	50	1000	Antistatic plastic tube				

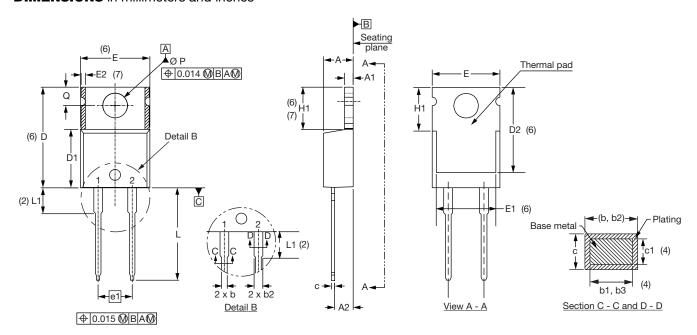
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96069				
Part marking information	www.vishay.com/doc?95391				
SPICE model	www.vishay.com/doc?96702				



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2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL		INC	INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
E1	6.86	8.89	0.270	0.350	6	
E2	-	0.76	-	0.030	7	
e1	4.88	5.28	0.192	0.208		
H1	5.84	6.86	0.230	0.270	6, 7	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØΡ	3.54	3.73	0.139	0.147		
Q	2.60	3.00	0.102	0.118		

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077

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